

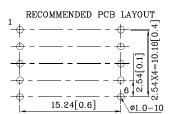
13.2mm(0.52") SINGLE DIGIT NUMERIC DISPLAY

Features

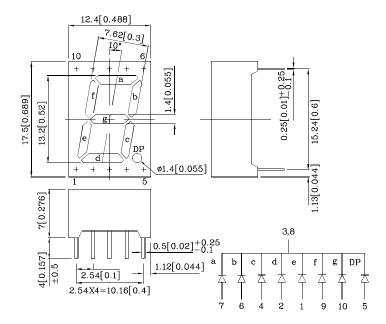
- Low power consumption
- ullet Robust package
- I.C. Compatible
- Standard configuration: Gray face w/ white segments
- \bullet Optional black face provides superior color contrast
- RoHS Compliant







Package Schematics



Notae

- 1. All dimensions are in millimeters (inches), Tolerance is $\pm 0.25 (0.01")$ unless otherwise noted.
- 2. Specifications are subject to change without notice.

Absolute Maximum Ratings (T _A =25°C)		UR (GaAsP/GaP)	Unit	
Reverse Voltage	V_{R}	5	V	
Forward Current	I_{F}	30	mA	
Forward Current (Peak) 1/10 Duty Cycle 0.1ms Pulse Width	ifs	160	mA	
Power Dissipation	P_{D}	75	mW	
Operating Temperature	T_{A}	-40 ~ +85	°C	
Storage Temperature	Tstg	-40 ~ +85	C	
Lead Solder Temperature [2mm Below Package Base]	1 1260°C For 3-5 Seconds			

Operating Characteristics (T _A =25°C)	UR (GaAsP/GaP)	Unit		
Forward Voltage (Typ.) (I _F =10mA)	V_{F}	1.9	V	
Forward Voltage (Max.) (I _F =10mA)	V_{F}	2.5	V	
Reverse Current (Max.) (V _R =5V)	I_R	10	uA	
Wavelength of Peak Emission CIE127-2007* (Typ.) (I _F =10mA)	λP	627*	nm	
Wavelength of Dominant Emission CIE127-2007* (Typ.) $(I_F=10\text{mA})$	λD 617*		nm	
Spectral Line Full Width At Half-Maximum (Typ.) (I _F =10mA)	$\triangle \lambda$	45	nm	
Capacitance (Typ.) (V _F =0V, f=1MHz)	С	15	pF	

Part Number	Emitting Color	Emitting Material	$\begin{array}{c} Luminous\ Intens\\ CIE127\text{-}2007*\\ (I_F\text{=}10\text{mA})\\ \text{ucd} \end{array}$	•	Description
			min. typ	•	
XDUR13C	Red	GaAsP/GaP	3000 6390 1400* 2490	697	Common Cathode, Rt.Hand Decimal.

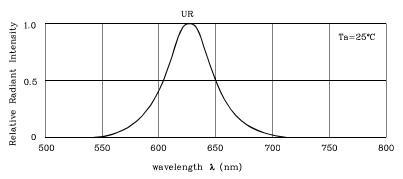
^{*}Luminous intensity value and wavelength are in accordance with CIE127-2007 standards.

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XDSA0208 V8-X Layout: Maggie L.

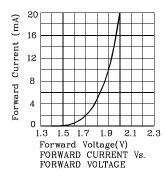


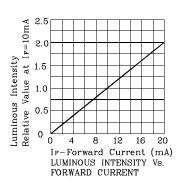


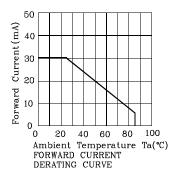


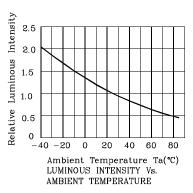
RELATIVE INTENSITY Vs. CIE WAVELENGTH

❖ UR

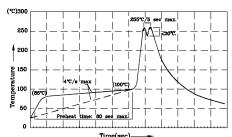








Wave Soldering Profile for Thru-Hole Products (Pb-Free Components)



- nmend pre-heat temperature of 105°C or less (as measured with a noccouple attached to the LED pins) prior to immersion in the solder with a maximum solder bath temperature of 250°C wave soldering temperature between 245°C \sim 255°C for 3 sec (5 sec
- 2.Peak wave soldering temperature between 2450 ~ 2500 in 3 550. max).
 3.Do not apply stress to the epoxy resin while the temperature is ab 4.Pixtures should not incur stress on the component when mounting during soldering process.
 5.SAC 305 solder alloy is recommended.
 6.No more than one wave soldering pass.

Remarks:

If special sorting is required (e.g. binning based on forward voltage, luminous intensity / luminous flux, or wavelength),

the typical accuracy of the sorting process is as follows:

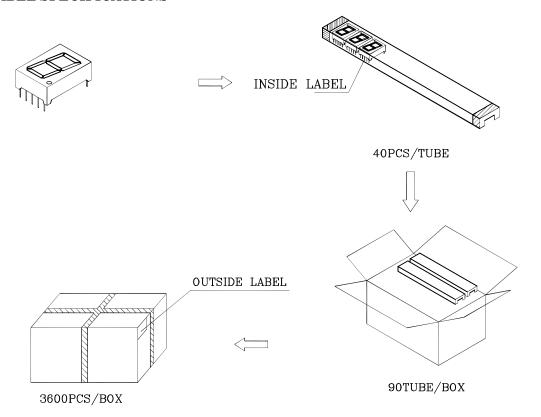
- 1. Wavelength: +/-1nm
- 2. Luminous Intensity / Luminous Flux: +/-15%
- 3. Forward Voltage: +/-0.1V

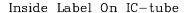
Note: Accuracy may depend on the sorting parameters.

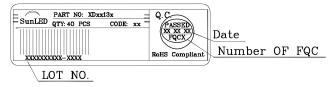




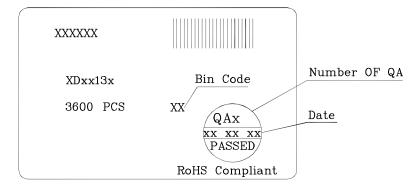
PACKING & LABEL SPECIFICATIONS







Outside Label On Box



TERMS OF USE

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- 2. Contents within this document are subject to improvement and enhancement changes without notice.
- 3. The product(s) in this document are designed to be operated within the electrical and environmental specifications indicated on the datasheet. User accepts full risk and responsibility when operating the product(s) beyond their intended specifications.
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- 5. The contents within this document may not be altered without prior consent by SunLED.
- $6. \ Additional\ technical\ notes\ are\ available\ at\ \underline{http://www.SunLEDusa.com/TechnicalNotes.asp}$

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